

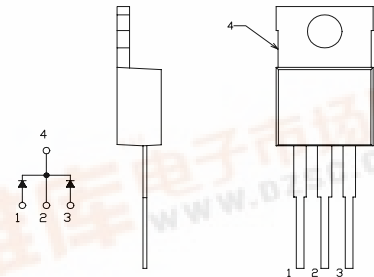


SBD Type : GCH30A10

OUTLINE DRAWING

FEATURES

- *Similar to TO-220AB Case
- *Dual Diodes – Cathode Common
- *Low Forward Voltage Drop
- *High Surge Capability
- *Tj=150 °C operation



Maximum Ratings

Approx Net Weight: 1.9g

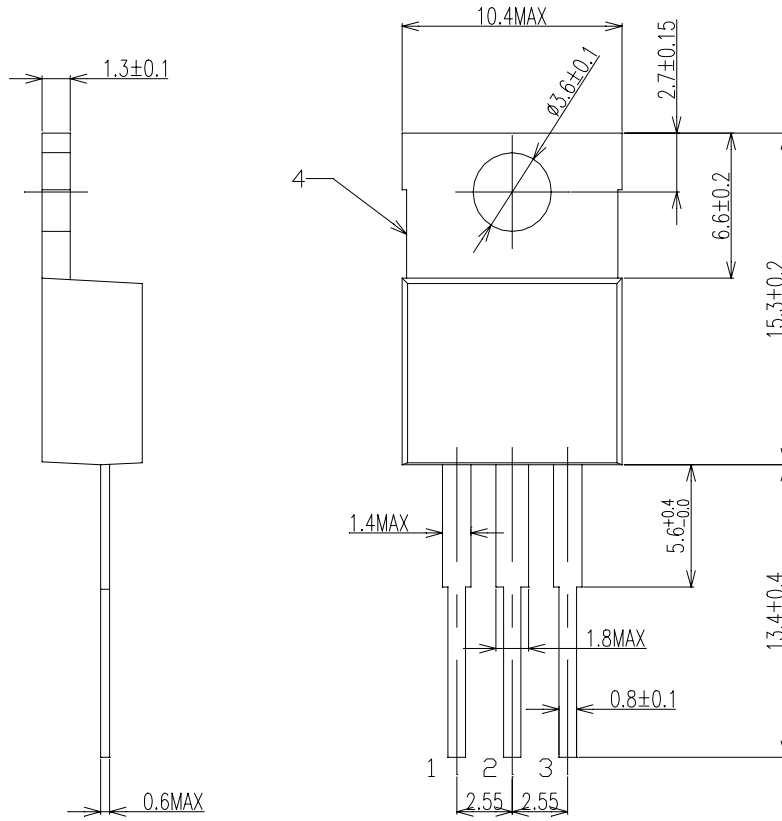
Rating	Symbol	GCH30A10			Unit
Repetitive Peak Reverse Voltage	V_{RRM}	100			V
Average Rectified Output Current	I_O	30	$T_c=105^\circ\text{C}$	50 Hz Full Sine Wave Resistive Load	A
RMS Forward Current	$I_{F(RMS)}$	33.3			A
Surge Forward Current	I_{FSM}	250	50Hz Full Sine Wave ,1cycle Non-repetitive		A
Operating JunctionTemperature Range	T_{jw}	-40 to +150			°C
Storage Temperature Range	T_{stg}	-40 to +150			°C
Mounting torque	Ftor	recommended torque = 0.5			N•m

Electrical • Thermal Characteristics

Characteristics	Symbol	Conditions	Min.	Typ.	Max.	Unit
Peak Reverse Current	I_{RM}	$T_j= 25^\circ\text{C}, V_{RM}= V_{RRM}$ per arm	-	-	2	mA
Peak Forward Voltage	V_{FM}	$T_j= 25^\circ\text{C}, I_{FM}= 15 \text{ A}$ per arm	-	-	0.88	V
Thermal Resistance	$R_{th(j-c)}$	Junction to Case	-	-	1.5	°C/W



GCH30A10 OUTLINE DRAWING (Dimensions in mm)



Center Tap

